



15C02MH

Bipolar Transistor 15V, 1A, Low VCE(sat) NPN Single MCPH3

ON Semiconductor®

<http://onsemi.com>

Applications

- Low-frequency amplifier, high-speed switching, small motor drive

Features

- Large current capacity
- Low collector-to-emitter saturation voltage (resistance) $R_{CE(sat)}$ typ.=300mΩ [$I_C=1A$, $I_B=50mA$]
- Ultrasmall package facilitates miniaturization in end products
- Small ON-resistance (R_{on})

Specifications

Absolute Maximum Ratings at $T_a=25^\circ C$

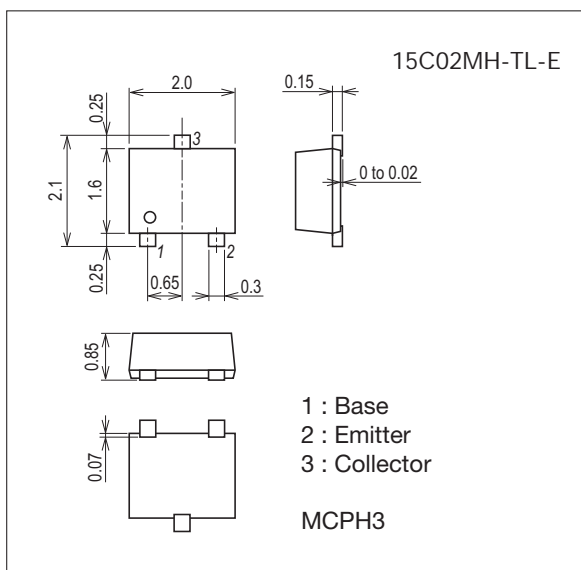
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		20	V
Collector-to-Emitter Voltage	V_{CEO}		15	V
Emitter-to-Base Voltage	V_{EBO}		5	V
Collector Current	I_C		1	A
Collector Current (Pulse)	I_{CP}		2	A
Collector Dissipation	P_C	When mounted on ceramic substrate (600mm ² ×0.8mm)	600	mW
Junction Temperature	T_j		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

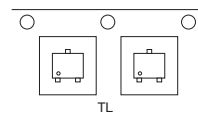
7019A-004



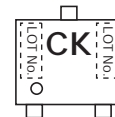
Product & Package Information

- Package : MCPH3
- JEITA, JEDEC : SC-70, SOT-323
- Minimum Packing Quantity : 3,000 pcs./reel

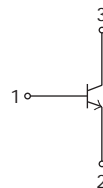
Packing Type : TL



Marking



Electrical Connection

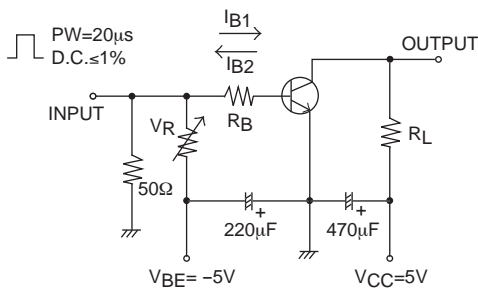


15C02MH

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=12V, I_E=0A$			100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4V, I_C=0A$			100	nA
DC Current Gain	h_{FE}	$V_{CE}=2V, I_C=50mA$	300		800	
Gain-Bandwidth Product	f_T	$V_{CE}=2V, I_C=50mA$		440		MHz
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$		4		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=400mA, I_B=20mA$		140	280	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=400mA, I_B=20mA$		0.9	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0A$	20			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	15			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0A$	5			V
Turn-ON Time	t_{on}	See specified Test Circuit.		30		ns
Storage Time	t_{stg}			165		ns
Fall Time	t_f			25		ns

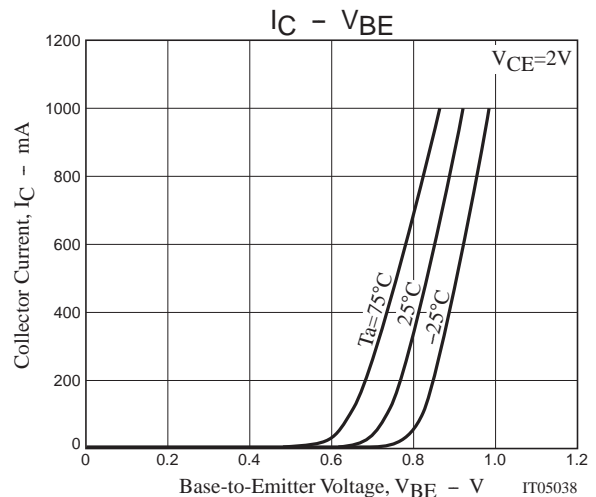
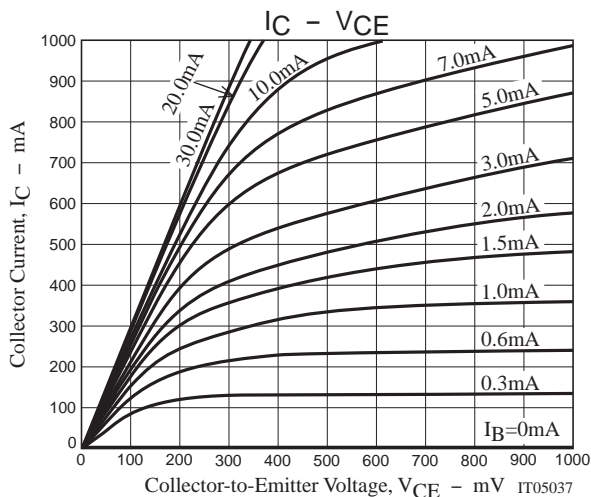
Switching Time Test Circuit



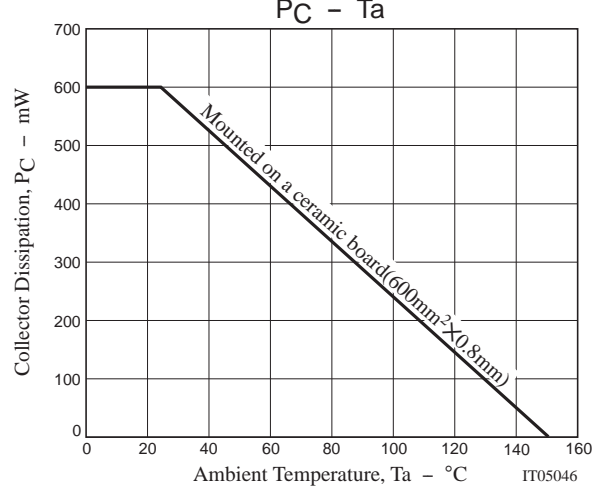
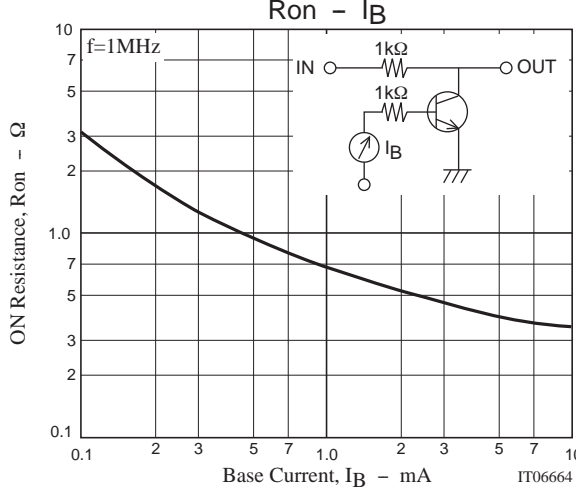
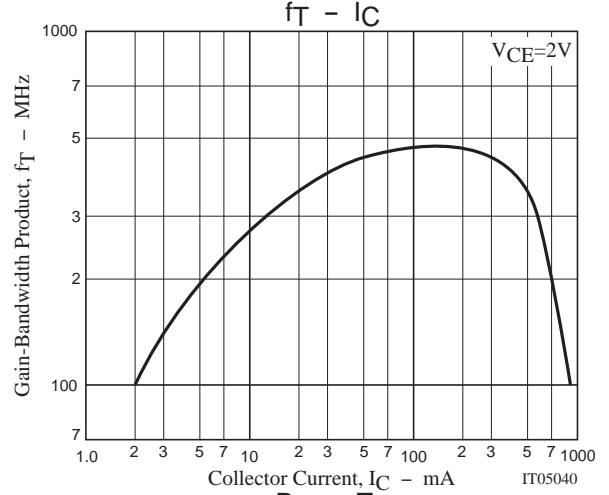
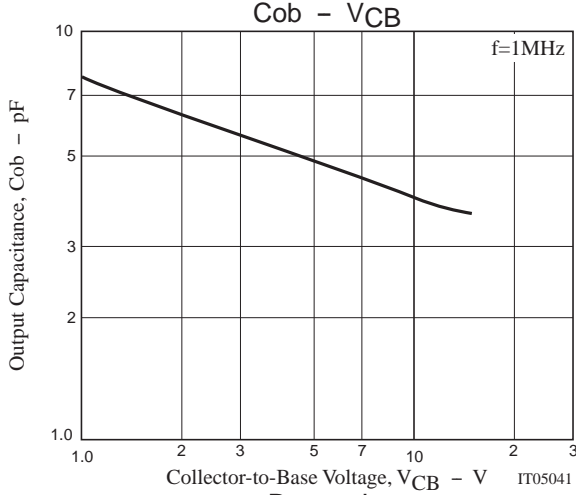
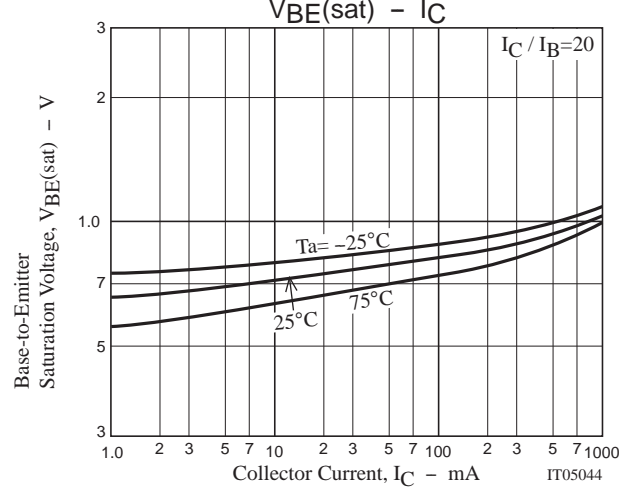
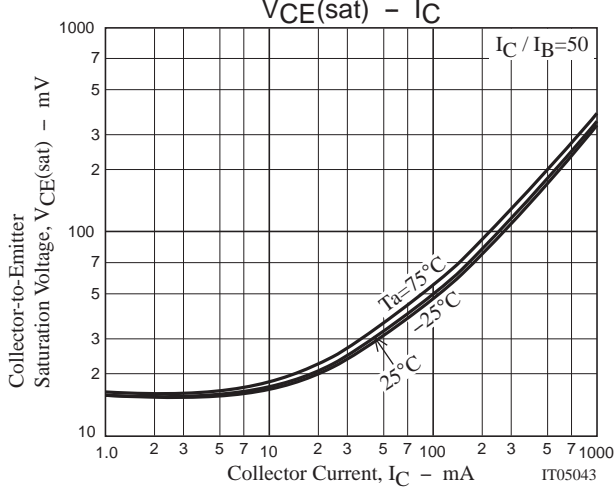
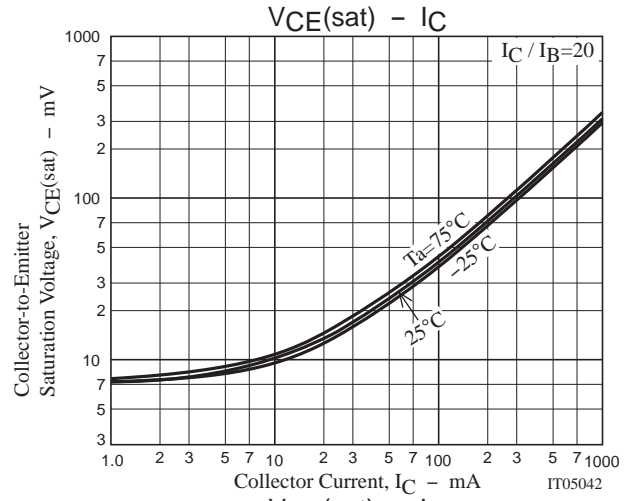
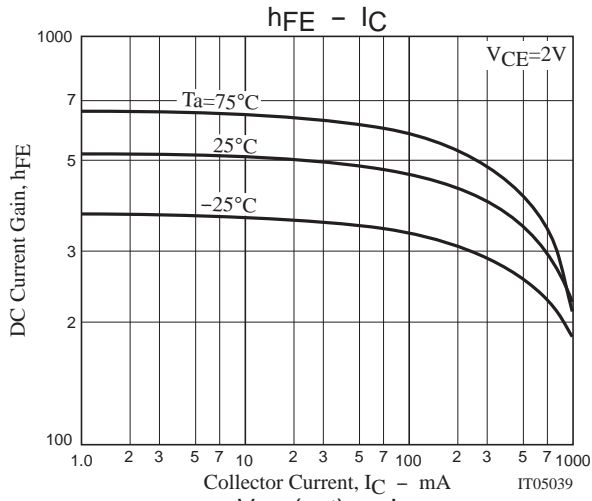
$$I_C = 20I_{B1} = -20I_{B2} = 400mA$$

Ordering Information

Device	Package	Shipping	memo
15C02MH-TL-E	MCPH3	3,000pcs./reel	Pb Free



15C02MH



Embossed Taping Specification

15C02MH-TL-E

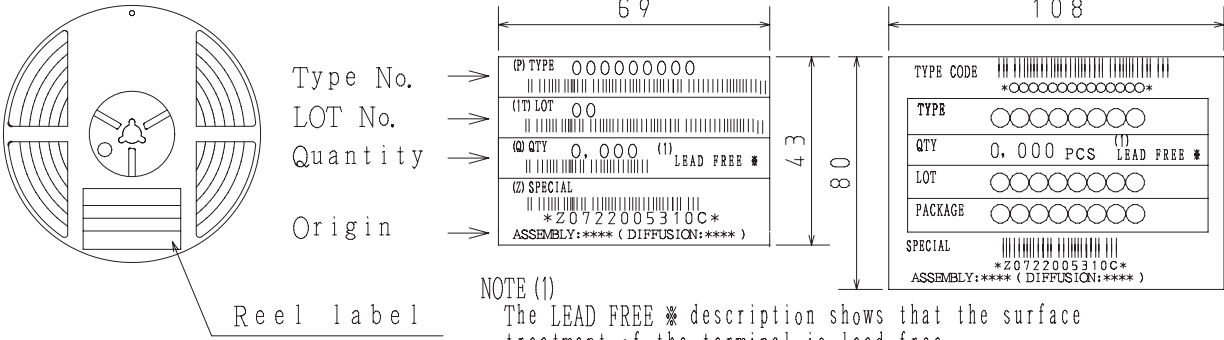
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
MCPH3	MCPH3	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method

Reel label, Inner box label (unit:mm) Outer box label

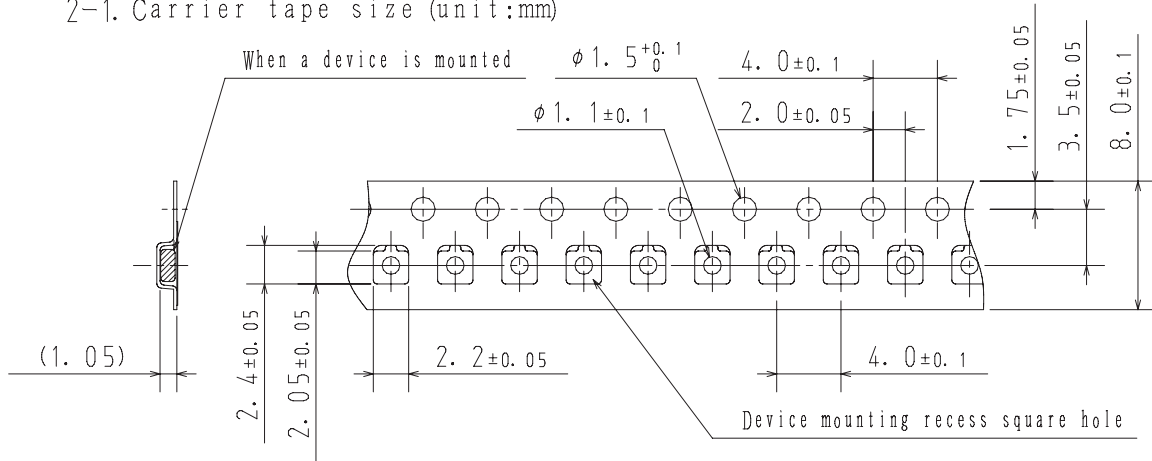
It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



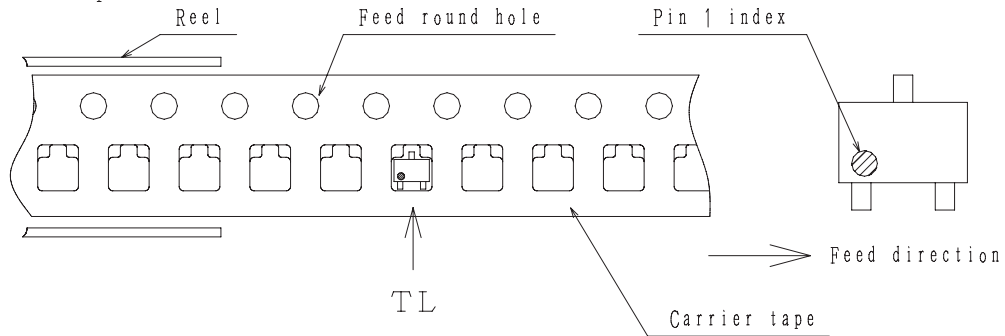
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



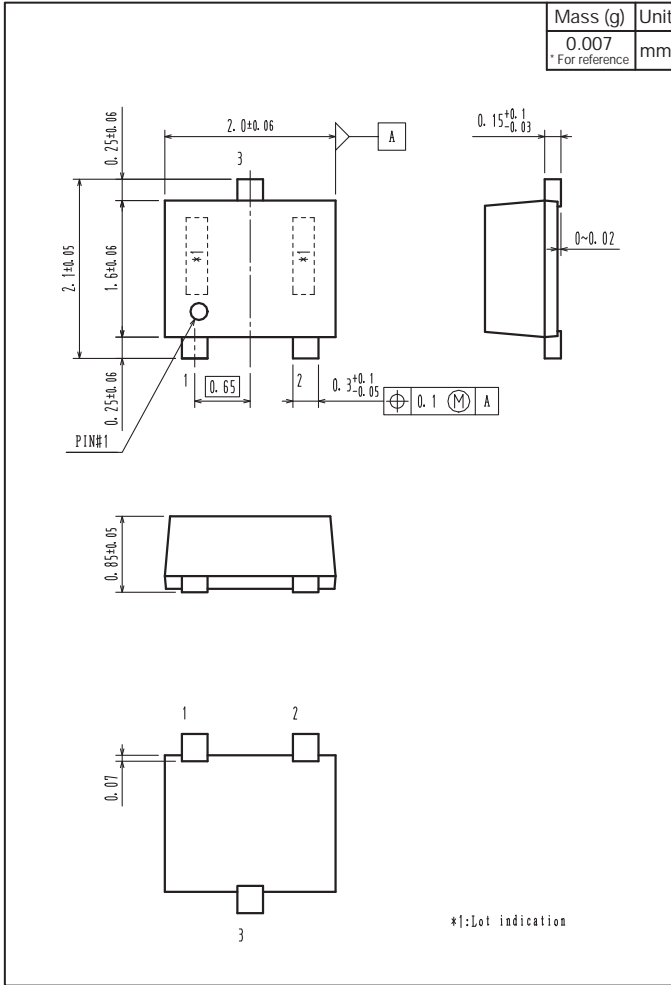
2-2. Device placement direction



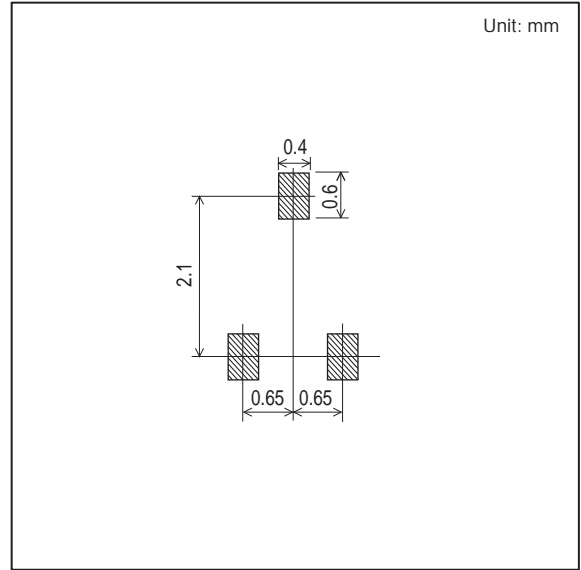
Those with pin 1 index on the feed hole side.....TL

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Outline Drawing 15C02MH-TL-E



Land Pattern Example



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